60 V, 6.0 A, Low V_{CE(sat)} NPN Transistor

ON Semiconductor's e^2 PowerEdge family of low $V_{CE(sat)}$ transistors are surface mount devices featuring ultra low saturation voltage ($V_{CE(sat)}$) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

Rating	Symbol	Мах	Unit			
Collector-Emitter Voltage	V _{CEO}	60	Vdc			
Collector-Base Voltage	V _{CBO}	100	Vdc			
Emitter-Base Voltage	V _{EBO}	6.0	Vdc			
Collector Current – Continuous	Ι _C	6.0	A			
Collector Current – Peak	I _{CM}	12.0	A			

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

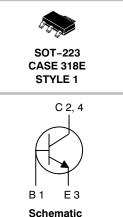
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



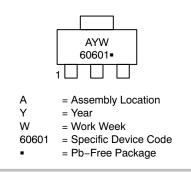
ON Semiconductor®

http://onsemi.com

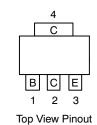
 $\begin{array}{c} \text{60 VOLTS, 6.0 AMPS} \\ \text{2.0 WATTS} \\ \text{NPN LOW } V_{\text{CE(sat)}} \text{ TRANSISTOR} \\ \text{EQUIVALENT } R_{\text{DS(on)}} \text{ 50 } \text{m}\Omega \end{array}$



MARKING DIAGRAM



PIN ASSIGNMENT



ORDERING INFORMATION

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D (Note 1)	800 6.5	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R _{θJA} (Note 1)	155	°C/W
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D (Note 2)	2 15.6	W mW/°C
Thermal Resistance, Junction-to-Ambient	R _{θJA} (Note 2)	64	°C/W
Total Device Dissipation (Single Pulse < 10 sec.)	P _{Dsingle} (Note 3)	710	mW
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

FR-4 @ 7.6 mm², 1 oz. copper traces.
FR-4 @ 645 mm², 1 oz. copper traces.

3. Thermal response.

ORDERING INFORMATION

Device	Package	Shipping [†]
NSS60601MZ4T1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel
NSV60601MZ4T1G*	SOT-223 (Pb-Free)	1,000 / Tape & Reel
NSS60601MZ4T3G	SOT-223 (Pb-Free)	4,000 / Tape & Reel
NSV60601MZ4T3G*	SOT-223 (Pb-Free)	4,000 / Tape & Reel

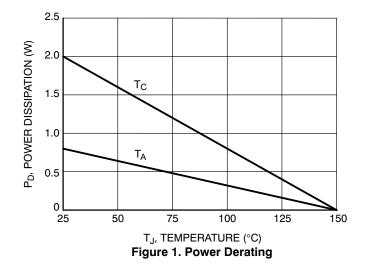
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

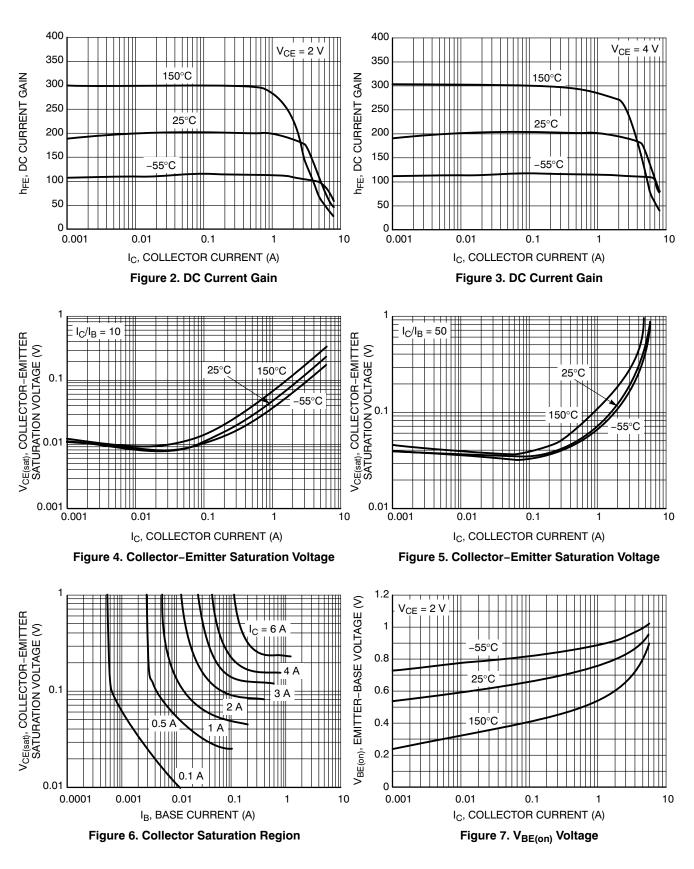
Capable.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

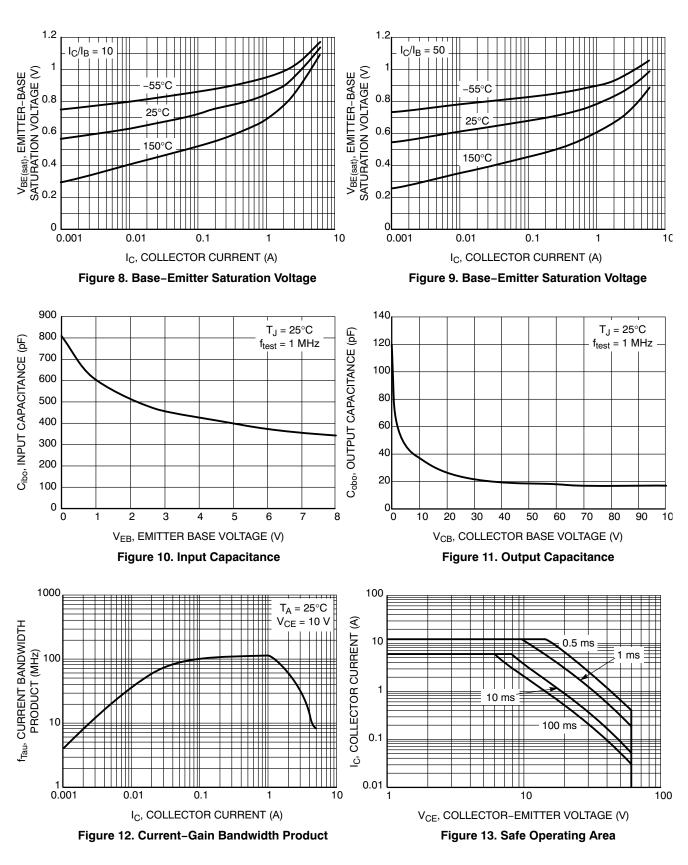
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•		•
Collector – Emitter Breakdown Voltage $(I_{C} = 10 \text{ mAdc}, I_{B} = 0)$	V _{(BR)CEO}	60	_	_	Vdc
Collector – Base Breakdown Voltage ($I_C = 0.1 \text{ mAdc}, I_E = 0$)	V _{(BR)CBO}	100	_	_	Vdc
Emitter – Base Breakdown Voltage ($I_E = 0.1 \text{ mAdc}, I_C = 0$)	V _{(BR)EBO}	6.0	_	_	Vdc
Collector Cutoff Current ($V_{CB} = 100 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	_	0.1	μAdc
Emitter Cutoff Current (V _{EB} = 6.0 Vdc)	I _{EBO}	-	-	0.1	μAdc
ON CHARACTERISTICS					
DC Current Gain (Note 4) (I _C = 500 mA, V _{CE} = 2.0 V) (I _C = 1.0 A, V _{CE} = 2.0 V) (I _C = 2.0 A, V _{CE} = 2.0 V) (I _C = 6.0 A, V _{CE} = 2.0 V)	h _{FE}	150 120 100 50	- - - -	- 360 - -	_
Collector – Emitter Saturation Voltage (Note 4) ($I_C = 0.1 A$, $I_B = 2.0 mA$) ($I_C = 1.0 A$, $I_B = 0.100 A$) ($I_C = 2.0 A$, $I_B = 0.200 A$) ($I_C = 3.0 A$, $I_B = 60 mA$) ($I_C = 6.0 A$, $I_B = 0.6 A$)	V _{CE(sat)}	- - - -	 0.045 0.085 	0.040 0.060 0.100 0.220 0.300	V
Base – Emitter Saturation Voltage (Note 4) $(I_C = 1.0 \text{ A}, I_B = 0.1 \text{ A})$	V _{BE(sat)}	_	_	0.900	V
Base – Emitter Turn–on Voltage (Note 4) ($I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}$)	V _{BE(on)}	_	_	0.900	V
Cutoff Frequency ($I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ MHz}$)	f _T	100	_	_	MHz
Input Capacitance (V _{EB} = 5.0 V, f = 1.0 MHz)	Cibo	-	400	-	pF
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	Cobo	-	37	-	pF
SWITCHING CHARACTERISTICS					
Delay (V _{CC} = 30 V, I _C = 750 mA, I _{B1} = 15 mA)	t _d	_	85	_	ns
Rise (V _{CC} = 30 V, I _C = 750 mA, I _{B1} = 15 mA)	tr	-	115	-	ns
Storage (V _{CC} = 30 V, I _C = 750 mA, I _{B1} = 15 mA)	t _s	-	1350	-	ns
Fall (V _{CC} = 30 V, I _C = 750 mA, I _{B1} = 15 mA)	t _f	-	125	-	ns

4. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle \leq 2%.



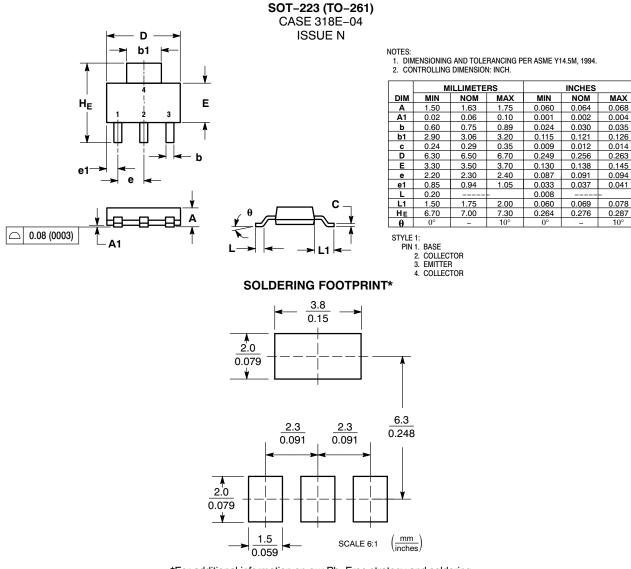


TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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